

LM339IDR LM339ITR LM339CDR LM339CTR

General-Purpose High-Voltage Open-Drain Output Quad Comparators

1 FEATURES

- Supply Range: +3.3V to +32V
- **Low Supply Current** $45\mu A$ (TYP) per channel at $V_S = 5V$
- Common-Mode Input Voltage Range **Includes Ground**
- **Low Output Saturation Voltage**
- **Open-Drain Output for Maximum Flexibility**
- SPECIFIED UP TO +125°C
- PACKAGES: SOIC14 TSSOP14

2 APPLICATIONS

- **Hysteresis Comparators**
- **Factory Automation & Control**
- **Industrial Equipment**
- **Test and Measurement**
- **Cordless Power Tool**
- **Vacuum Robot**
- Wireless Infrastructure

3 DESCRIPTIONS

The LM339 is the quad comparators version, and the outputs can be connected to other open-collector outputs to achieve wired-AND relationships. It can operate from 3.3V to 32V, and have low power consuming 45µA (TYP) per channel.

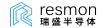
The LM339 consistof four independent voltage comparators that are designed to operate from a single power supply over a wide range of voltages. Quiescent current is independent of the supply voltage. The device is the most cost-effective solutions for applications where low offset voltage, high supply voltage capability, low supply current, and space saving are the primary specifications in circuit design for portable consumer products.

The LM339 is available in Green SOIC14, TSSOP14 packages. It operates over an ambient temperature range of -40°C to +125°C.

Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM339IDR LM339CDR	SOIC14	8.65mm×3.90mm
LM339ITR LM339CTR	TSSOP14	5.00mm×4.40mm

For all available packages, see the orderable addendum at the end of the data sheet.



5 PACKAGE/ORDERING INFORMATION (1)

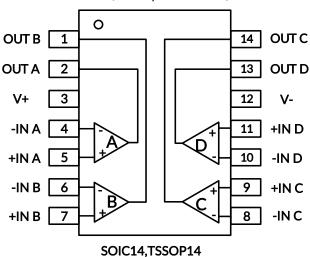
Orderable Device	Package Type	Pin	Channel	Op Temp(°C)	Device Marking ⁽²⁾	MSL ⁽³⁾	Package Qty
LM339IDR/CDR	SOIC14	14	4	-40°C ~+125°C	LM339CDR/IDR	MSL3	Tape and Reel, 4000
LM339ITR/CTR	TSSOP14	14	4	-40°C ~+125°C	LM339ITR/CTR	MSL3	Tape and Reel, 4000

NOTE:

- (1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.
- (2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.
- (3) MSL, The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications.

6 Pin Configuration and Functions (Top View)

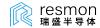
LM339IDR/CDR, LM339ITR/CTR



Pin Description

i iii Descrip	iii Description							
NANAE	PIN	1.(0.(1)	DESCRIPTION					
NAME	SOIC14,TSSOP14	I/O (1)	DESCRIPTION					
OUTB	1	0	Output, channel B					
OUTA	2	0	Output, channel A					
V+	3	Р	Positive (highest) power supply					
-INA	4	I	Inverting input, channel A					
+INA	5	ı	Noninverting input, channel A					
-INB	6	ı	Inverting input, channel B					
+INB	7	ı	Noninverting input, channel B					
-INC	8	I	Inverting input, channel C					
+INC	9	ı	Noninverting input, channel C					
-IND	10	ı	Inverting input, channel D					
+IND	11	ı	Noninverting input, channel D					
V-	12	Р	Negative (lowest) power supply					
OUTD	13	0	Output, channel D					
OUTC	14	0	Output, channel C					

⁽¹⁾ I=Input, O=Output, P=Power.



7 SPECIFICATIONS

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT	
	Supply, V _S =(V+) - (V-)		36			
Voltage	Input pin (IN+, IN-) (2)		(V-)-0.3	(V+) +0.3	V	
	Signal output pin ⁽³⁾		(V-)-0.3	(V+) +0.3		
	Signal input pin (IN+, IN-) (2)	-10	10	mA		
Current	Signal output pin ⁽³⁾	-55	55	mA		
	Output short-circuits (4)	Conti	Continuous			
0	D1 (5)	SOP14		105	0C ()A/	
ALθ	Package thermal impedance (5) TSSOP14			90	°C/W	
	Operating range, T _A	-40	125			
Temperature	Junction, T _J ⁽⁶⁾	-40	150	°C		
	Storage, T _{stg}	Storage, T _{stg}				

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to 10mA or less.
- (3) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.3V beyond the supply rails should be current-limited to ±55mA or less.
- (4) Short-circuit from output to V_{CC} can cause excessive heating and eventual destruction.
- (5) The package thermal impedance is calculated in accordance with JESD-51.
- (6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

			VALUE	UNIT
		Human-Body Model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	±2000	
V _(ESD)	Electrostatic discharge	Charged-Device Model (CDM), per ANSI/ESDA/JEDEC JS-002 (2)	±1500	V
		Machine Model (MM)	±200	

⁽¹⁾ JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.



ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Supply valtage V = (VI) (V)	Single-supply	3.3		32	\/
Supply voltage, V _S = (V+) - (V-)	Dual-supply	±1.65		±16	V

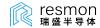


7.4 ELECTRICAL CHARACTERISTICS

(At $T_A = +25$ °C, $V_{CM}=(V_S/2)$, $V_S=5V$, unless otherwise noted.) (1)

	PARAMETER			LM339IDF	R/CDR,LM3	39ITR/CTR	LINUTC
	PARAMETER		CONDITIONS	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNITS
Vs	Operating Voltage Range			3.3		32	V
			V _S =5V, no load		180	360	
ΙQ	Quiescent Current		V _S =32V, no load, T _A =-40°C to +125°C		220		μΑ
			V _S =5V to 32V	-4.5	±0.8	4.5	
Vos	Input offset voltage		V _S =5V to 32V T _A =-40°C to +125°C	-5		5	mV
	Input Bios Current (4)(5)		T _A =25°C		10	50	pА
IB	Input Bias Current (4) (5)		T _A =-40°C to +125°C			100	nA
	nput Offset Current (4)		T _A =25°C		10	50	pА
los	Input Offset Current (4)		T _A =-40°C to +125°C			100	nA
			V _S =3.3V to 32V	(V-)		(V+)-1.5	
V_{CM}	Common-Mode Voltage Range		V _s =3.3V to 32V T _A =-40°C to +125°C	(V-)		(V+)-2.0	V
Avd	Large signal differential voltage amplification		V _S =15V, Vo=1.4V to 11.4V R _L ≥15k to (V+)	50	200		V/mV
V_{OL}	Low-Level output voltage		I _{sink} ≤4mA, V _{ID} =-1V		200	300	mV
l _{OL}	Output Current(sinking)		V _O =1.5V; V _{ID} =-1V; V _S =5V	9	23		mA
			(V+) =Vo=5V; V _{ID} =1V		80	400	nA
I _{OH-LKG}	High-Level Output Leakage	Current	(V+) =Vo=32V; V _{ID} =1V		100	500	nA
Switchin	ng Characteristics		<u> </u>	•		•	
		\	RPU=5.1KΩ, Overdrive =10mV		2.0		
-	Propagation Delay H To L	V _S =5V	RPU= $5.1K\Omega$, Overdrive = $100mV$		0.4		
T _{PHL}	(6)	V _S =32V	RPU= $5.1K\Omega$, Overdrive = $10mV$		2.2		
		V _S =32V	RPU= $5.1K\Omega$, Overdrive = $100mV$		0.4		
		\/ 5\/	RPU=5.1KΩ, Overdrive =10mV		2.5		μs
T	Propagation Delay L To H	V _S =5V	RPU= $5.1K\Omega$, Overdrive = $100mV$		0.8		
T_PLH	(6)	V _S =32V	RPU= $5.1K\Omega$, Overdrive = $10mV$		2.2		
		V _S =32V	RPU= $5.1K\Omega$, Overdrive = $100mV$		0.7		

- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.
- (4) This parameter is ensured by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.
- (6) High-to-low and low-to-high refers to the transition at the input.



7.5 TYPICAL CHARACTERISTICS

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S =5V, R_{PULLUP} =5.1k, V_{CM} = V_S /2, C_L =15pF, unless otherwise noted.

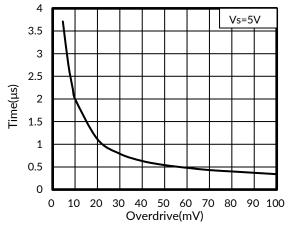


Figure 1. Response Time vs Input Overdrives
Negative Transition

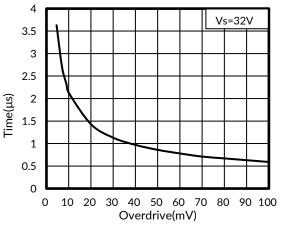


Figure 3. Response Time vs Input Overdrives
Negative Transition

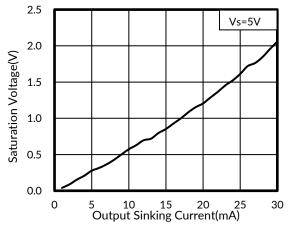


Figure 5. Saturation Voltage vs Output Sink Current

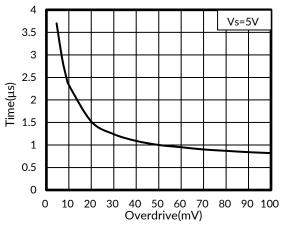


Figure 2. Response Time vs Input Overdrives
Positive Transition

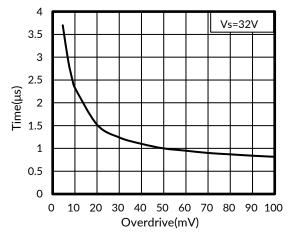


Figure 4. Response Time vs Input Overdrives
Positive Transition

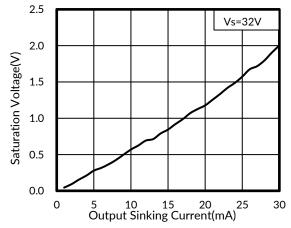


Figure 6. Saturation Voltage vs Output Sink Current



8 Detailed Description

8.1 Overview

The LM339 family of comparators can operate up to 32V on the supply pin. This standard device has proven ubiquity and versatility across a wide range of applications. This is due to its low power and high speed. The open-drain output allows the user to configure the output's logic low voltage (V_{OL}) and can be utilized to enable the comparator to be used in AND functionality.

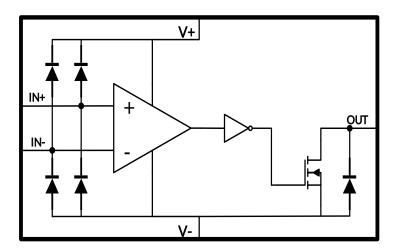


Figure 7. Functional Block Diagram



9 Application and Implementation

9.1 Application Information

LM339 is typically used to compare a single signal to a reference or two signals against each other. Many users take advantage of the open drain output (logic high with pull-up) to drive the comparison logic output to a logic voltage level to an MCU or logic device. The wide supply range and high voltage capability makes this comparator optimal for level shifting to a higher or lower voltage.

9.2 Typical Application

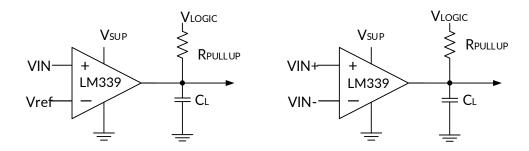


Figure 8. Single-Ended and Differential Comparator Configurations

9.3 Detailed Design Procedure

When using the device in a general comparator application, determine the following:

- Input Voltage Range
- Minimum Overdrive Voltage
- Output and Drive Current
- Response Time

9.4 Input Voltage Range

When choosing the input voltage range, the input common mode voltage range (V_{ICR}) must be taken in to account. If temperature operation is below 25°C the V_{ICR} can range from 0 V to V_{CC} – 2.0 V. This limits the input voltage range to as high as V_{CC} – 2.0 V and as low as 0 V. Operation outside of this range can yield incorrect comparisons.



10 Layout

10.1 Layout Guidelines

For accurate comparator applications without hysteresis, it is important maintain a stable power supply with minimized noise and glitches. To achieve this, it is best to add a bypass capacitor between the supply voltage and ground. This should be implemented on the positive power supply and negative supply (if available). If a negative supply is not being used, do not put a capacitor between the IC's GND pin and system ground. Minimize coupling between outputs and inverting inputs to prevent output oscillations. Do not run output and inverting input traces in parallel unless there is a $V_{\rm CC}$ or GND trace between output and inverting input traces to reduce coupling. When series resistance is added to inputs, place resistor close to the device.

10.2 Layout Example

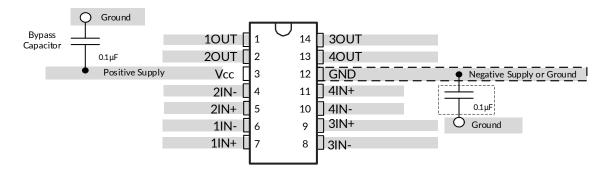
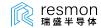
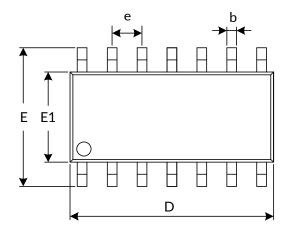


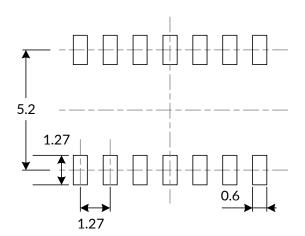
Figure 9. LM339 Layout Example



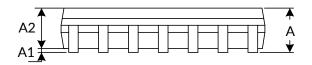
11 PACKAGE OUTLINE DIMENSIONS

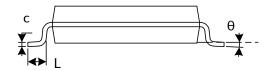
SOIC14





RECOMMENDED LAND PATTERN (Unit: mm)



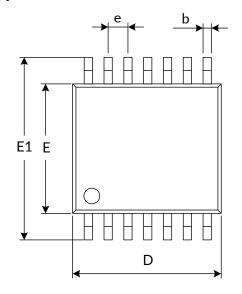


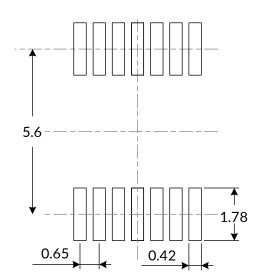
Complete	Dimensions I	n Millimeters	Dimension	s In Inches
Symbol	Min Max		Min	Max
A (1)	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.310	0.510	0.012	0.020
С	0.100	0.250	0.004	0.010
D (1)	8.450	8.850	0.333	0.348
е	1.270(BSC) (2)	0.050(BSC) (2)
Е	5.800	6.200	0.228	0.244
E1 ⁽¹⁾	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.



TSSOP14(3)





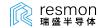
RECOMMENDED LAND PATTERN (Unit: mm)





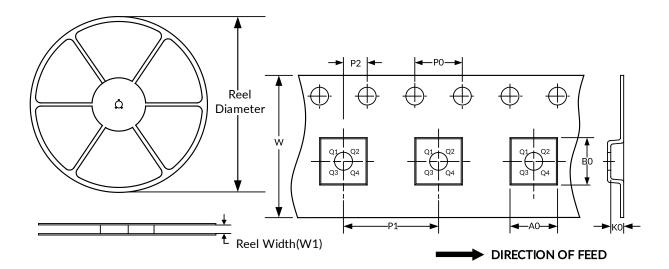
Complete	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Мах	Min	Max	
A (1)		1.200		0.047	
A1	0.050	0.150	0.002	0.006	
A2	0.800	1.050	0.031	0.041	
b	0.190	0.300	0.007	0.012	
С	0.090	0.200	0.004	0.008	
D (1)	4.860	5.100	0.191	0.201	
E ⁽¹⁾	4.300	4.500	0.169	0.177	
E1	6.250	6.550	0.246	0.258	
е	0.650(BSC) (2)	0.026(BSC) (2)	
L	0.500	0.700	0.020	0.028	
Н	0.25	(TYP)	0.01(TYP)		
θ	1°	7°	1° 7°		

- Plastic or metal protrusions of 0.15mm maximum per side are not included.
 BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.



12 TAPE AND REEL INFORMATION REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP14	13"	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1

- 1. All dimensions are nominal.
- 2. Plastic or metal protrusions of 0.15mm maximum per side are not included.